L Number	Hits	Search Text	DB	Time stamp
117	52	(chemical adj reaction) same semiconductor same surface	USPAT;	2004/09/14 13:33
		same electron same energy	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
118	1	3925235.URPN.	USPAT	2004/09/14 13:33
119	1	"3493889".PN.	USPAT	2004/09/14 13:33
120	72	semiconductor same surface same energy same laser same	USPAT;	2004/09/14 13:35
		excited	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
121	28	semiconductor same surface same energy same laser same	USPAT;	2004/09/14 13:35
		(chemical adj reaction)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	37	zuppero-a\$.in.	USPAT;	2004/09/14 11:36
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1	("6700056").PN.	USPAT	2004/09/14 10:50
-	3	(("5641585") or ("5593509") or ("4793799")).PN.	USPAT	2004/09/14 12:24
<del>-</del>	5	(("4045359") or ("4407705") or ("5587827") or ("3694770")	USPAT	2004/09/14 12:50
		or ("5048042")).PN.		
-	0	(excited adj carrier) same semiconductor same cataly\$7	USPAT;	2004/09/14 12:52
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	400		IBM_TDB	
-	180	(excited adj carrier) same semiconductor	USPAT;	2004/09/14 12:59
			US-PGPUB;	
			EPO; JPO;	·
			DERWENT;	
		Administration of the second s	IBM_TDB	
-	167	(chemical adj reaction) same semiconductor same surface	USPAT;	2004/09/14 13:23
		same electron	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	